

CD4511BM/CD4511BC BCD-to-7 Segment Latch/Decoder/Driver

General Description

The CD4511BM/CD4511BC BCD-to-seven segment latch/decoder/driver is constructed with complementary MOS (CMOS) enhancement mode devices and NPN bipolar output drivers in a single monolithic structure. The circuit provides the functions of a 4-bit storage latch, an 8421 BCD-to-seven segment decoder, and an output drive capability. Lamp test (LT), blanking (BI), and latch enable (LE) inputs are used to test the display, to turn-off or pulse modulate the brightness of the display, and to store a BCD code, respectively. It can be used with seven-segment light emitting diodes (LED), incandescent, fluorescent, gas discharge, or liquid crystal readouts either directly or indirectly.

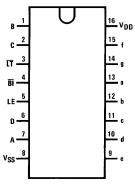
Applications include instrument (e.g., counter, DVM, etc.) display driver, computer/calculator display driver, cockpit display driver, and various clock, watch, and timer uses.

Features

- Low logic circuit power dissipation
- High current sourcing outputs (up to 25 mA)
- Latch storage of code
- Blanking input
- Lamp test provision
- \blacksquare Readout blanking on all illegal input combinations
- Lamp intensity modulation capability
- Time share (multiplexing) facility
- Equivalent to Motorola MC14511

Connection Diagram

Dual-In-Line Package



TL/F/5991-1

Top View
Order Number CD4511B

Segment Identification



TL/F/5991-3

Truth Table

	Inputs					Outputs								
LE	BI	ΙŢ	D	С	В	Α	а	b	С	d	е	f	g	Display
X	Х	0	Х	Χ	Χ	Χ	1	1	1	1	1	1	1	В
X	0	1	X	Χ	Χ	Χ	0	0	0	0	0	0	0	
0	1	1	0	0	0	0	1	1	1	1	1	1	0	0
0	1	1	0	0	0	1	0	1	1	0	0	0	0	1
0	1	1	0	0	1	0	1	1	0	1	1	0	1	2
0	1	1	0	0	1	1	1	1	1	1	0	0	1	3
0	1	1	0	1	0	0	0	1	1	0	0	1	1	4
0	1	1	0	1	0	1	1	0	1	1	0	1	1	5
0	1	1	0	1	1	0	0	0	1	1	1	1	1	6
0	1	1	0	1	1	1	1	1	1	0	0	0	0	7
0	1	1	1	0	0	0	1	1	1	1	1	1	1	8
0	1	1	1	0	0	1	1	1	1	0	0	1	1	9
0	1	1	1	0	1	0	0	0	0	0	0	0	0	
0	1	1	1	0	1	1	0	0	0	0	0	0	0	
0	1	1	1	1	0	0	0	0	0	0	0	0	0	
0	1	1	1	1	0	1	0	0	0	0	0	0	0	
0	1	1	1	1	1	0	0	0	0	0	0	0	0	İ
0	1	1	1	1	1	1	0	0	0	0	0	0	0	
1	1	1	X	Х	Х	Χ				*				*

X = Don't Care

*Depends upon the BCD code applied during the 0 to 1 transition of LE.

Display



TL/F/5991-2

Absolute Maximum Ratings (Notes 1 & 2)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

DC Supply Voltage (V_{DD}) -0.5V to +18V Input Voltage (V_{IN}) -0.5V to V_{DD} +0.5V Storage Temperature Range (T_S) -65°C to +150°C

Power Dissipation (PD)

Dual-In-Line 700 mW Small Outline 500 mW

Lead Temperature (T_L) (Soldering, 10 seconds)

Recommended Operating

Conditions (Note 2)

DC Supply Voltage (V_{DD}) 3V to 15V Input Voltage (V_{IN}) 0V to V_{DD}

Operating Temperature Range (T_A) CD4510BM, CD4516BM CD4510BC, CD4516BC

-55°C to +125°C -40°C to +85°C

DC Electrical Characteristics CD4511BM

Symbol	Parameter	Conditions		−55°C		+ 25°C			+ 125°C	
Symbol	Farameter	Conditions	Min	Max	Min	Тур	Max	Min	Max	Units
I _{DD}	Quiescent	$V_{DD} = 5V$, $V_{IN} = V_{DD}$ or V_{SS}		5			5		150	μΑ
	Supply Current	$V_{DD} = 10V$, $V_{IN} = V_{DD}$ or V_{SS}		10			10		300	μA
		$V_{DD} = 15V$, $V_{IN} = V_{DD}$ or V_{SS}		20			20		600	μΑ
VOL	Output Voltage	$V_{DD} = 5V$		0.01		0	0.01		0.05	٧
02	Logical "0"	V _{DD} = 10V	•	0.01		0	0.01		0.05	V
	Level	$V_{DD} = 15V$		0.01		0	0.01		0.05	V
V _{OH}	Output Voltage	$V_{DD} = 5V$	4.1		4.1	4.57		4.1		V
	Logical "1"	$V_{DD} = 10V$	9.1		9.1	9.58		9.1		V
	Level	$V_{DD} = 15V$	14.1		14.1	14.59		14.1		V
V_{IL}	Low Level	$V_{DD} = 5V, V_{OUT} = 3.8V \text{ or } 0.5V$		1.5		2	1.5		1.5	V
	Input Voltage	$V_{DD} = 10V, V_{OUT} = 8.8V \text{ or } 1.0V$		3.0		4	3.0		3.0	V
		$V_{DD} = 15V, V_{OUT} = 13.8V \text{ or } 1.5V$		4.0		6	4.0		4.0	V
V_{IH}	High Level	$V_{DD} = 5V, V_{OUT} = 0.5V \text{ or } 3.8V$	3.5		3.5	3		3.5		V
	Input Voltage	$V_{DD} = 10V, V_{OUT} = 1.0V \text{ or } 8.8V$	7.0		7.0	6		7.0		V
		$V_{DD} = 15V, V_{OUT} = 1.5V \text{ or } 13.8V$	11.0		11.0	9		11.0		V
V _{OH}	Output	$V_{DD} = 5V$, $I_{OH} = 0$ mA	4.1		4.1	4.57		4.1		V
	(Source) Drive	$V_{DD} = 5V$, $I_{OH} = 5 \text{ mA}$				4.24				V
	Voltage	$V_{DD} = 5V$, $I_{OH} = 10 \text{ mA}$	3.9		3.9	4.12		3.5		V
		$V_{DD} = 5V, I_{OH} = 15 \text{ mA}$				3.94				V
		$V_{DD} = 5V, I_{OH} = 20 \text{ mA}$	3.4		3.4	3.75		3.0		V V
		$V_{DD} = 5V$, $I_{OH} = 25 \text{ mA}$				3.54				
		$V_{DD} = 10V, I_{OH} = 0 \text{ mA}$	9.1		9.1	9.58		9.1		V
		$V_{DD} = 10V, I_{OH} = 5 \text{ mA}$	9.0		9.0	9.26 9.17		8.6		V V
		$V_{DD} = 10V, I_{OH} = 10 \text{ mA}$ $V_{DD} = 10V, I_{OH} = 15 \text{ mA}$	9.0		9.0	9.17 9.04		8.6		V V
		$V_{DD} = 10V, I_{OH} = 20 \text{ mA}$	8.6		8.6	8.9		8.2		v
		$V_{DD} = 10V, I_{OH} = 25 \text{ mA}$	0.0		0.0	8.75		0.2		v
		V _{DD} = 15V, I _{OH} = 0 mA	14.1		14.1	9.58		14.1		v
		$V_{DD} = 15V, I_{OH} = 5 \text{ mA}$				14.27				v
		$V_{DD} = 15V, I_{OH} = 10 \text{ mA}$	14.0		14.0	14.17		13.6		V
		$V_{DD} = 15V, I_{OH} = 15 \text{ mA}$				14.07				V
		$V_{DD} = 15V, I_{OH} = 20 \text{ mA}$	13.6		13.6	13.95		13.2		V
		$V_{DD} = 15V, I_{OH} = 25 \text{ mA}$				13.8				V
l _{OL}	Low Level	$V_{DD} = 5V, V_{OL} = 0.4V$	0.64		0.51	0.88		0.36		mA
	Output Current	$V_{DD} = 10V, V_{OL} = 0.5V$	1.6		1.3	2.25		0.9		mA
		$V_{DD} = 15V, V_{OL} = 1.5V$	4.2		3.4	8.8		2.4		mA
I_{IN}	Input Current	$V_{DD} = 15V, V_{IN} = 0V$		-0.10		-10^{-5}	-0.10		-1.0	μΑ
		$V_{DD} = 15V, V_{IN} = 15V$		0.10		10-5	0.10		1.0	μΑ

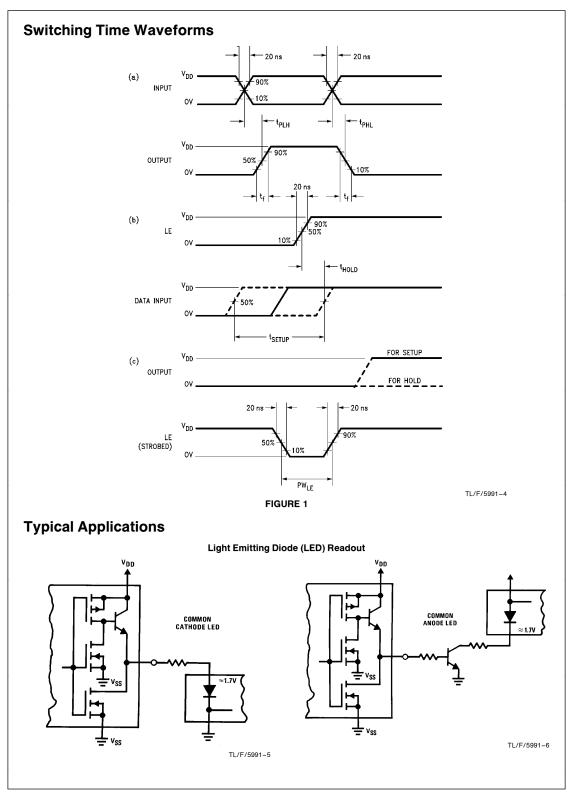
260°C

Symbol	Parameter	Conditions	-5	−55°C		+ 25°C		+85°C		Unite
Syllibol	Parameter	Conditions	Min	Max	Min	Тур	Max	Min	Max	Units
I _{DD}	Quiescent Supply Current	$V_{DD} = 5V$ $V_{DD} = 10V$ $V_{DD} = 15V$		20 40 80			20 40 80		150 300 600	μΑ μΑ μΑ
V _{OL}	Output Voltage Logical "0" Level	V _{DD} = 5V V _{DD} = 10V V _{DD} = 15V		0.01 0.01 0.01		0 0 0	0.01 0.01 0.01		0.05 0.05 0.05	V
V _{OH}	Output Voltage Logical "1" Level	$V_{DD} = 5V$ $V_{DD} = 10V$ $V_{DD} = 15V$	4.1 9.1 14.1		4.1 9.1 14.1	4.57 9.58 14.59		4.1 9.1 14.1		V V V
V _{IL}	Low Level Input Voltage	V _{DD} = 5V, V _{OUT} = 3.8V or 0.5V V _{DD} = 10V, V _{OUT} = 8.8V or 1.0V V _{DD} = 15V, V _{OUT} = 13.8V or 1.5V		1.5 3.0 4.0		2 4 6	1.5 3.0 4.0		1.5 3.0 4.0	V V V
V _{IH}	High Level Input Voltage	V _{DD} = 5V, V _{OUT} = 0.5V or 3.8V V _{DD} = 10V, V _{OUT} = 1.0V or 8.8V V _{DD} = 15V, V _{OUT} = 1.5V or 13.8V	3.5 7.0 11.0		3.5 7.0 11.0	3 6 9		3.5 7.0 11.0		V V V
V _{OH}	Output (Source) Drive Voltage	$V_{DD} = 5V, I_{OH} = 0 \text{ mA}$ $V_{DD} = 5V, I_{OH} = 5 \text{ mA}$ $V_{DD} = 5V, I_{OH} = 10 \text{ mA}$ $V_{DD} = 5V, I_{OH} = 15 \text{ mA}$ $V_{DD} = 5V, I_{OH} = 20 \text{ mA}$ $V_{DD} = 5V, I_{OH} = 25 \text{ mA}$	4.1 3.6 2.8		4.1 3.6 2.8	4.57 4.24 4.12 3.94 3.75 3.54		4.1 3.3 2.5		>
		V _{DD} = 10V, I _{OH} = 0 mA V _{DD} = 10V, I _{OH} = 5 mA V _{DD} = 10V, I _{OH} = 10 mA V _{DD} = 10V, I _{OH} = 15 mA V _{DD} = 10V, I _{OH} = 20 mA V _{DD} = 10V, I _{OH} = 25 mA	9.1 8.75 8.1		9.1 8.75 8.1	9.58 9.26 9.17 9.04 8.9 8.75		9.1 8.45 7.8		V V V V
		V _{DD} = 15V, I _{OH} = 0 mA V _{DD} = 15V, I _{OH} = 5 mA V _{DD} = 15V, I _{OH} = 10 mA V _{DD} = 15V, I _{OH} = 15 mA V _{DD} = 15V, I _{OH} = 20 mA V _{DD} = 15V, I _{OH} = 25 mA	14.1 13.75 13.1		14.1 13.75 13.1	14.59 14.27 14.18 14.07 13.95 13.8		14.1 13.45 12.8		V V V V
l _{OL}	Low Level Output Current	$V_{DD} = 5V, V_{OL} = 0.4V$ $V_{DD} = 10V, V_{OL} = 0.5V$ $V_{DD} = 15V, V_{OL} = 1.5V$	0.52 1.3 3.6		0.44 1.1 3.0	0.88 2.25 8.8		0.36 0.9 2.4		mA mA mA
I _{IN}	Input Current	V _{DD} = 15V, V _{IN} = 0V V _{DD} = 15V, V _{IN} = 15V		-0.30 0.30		-10 ⁻⁵	-0.30 0.30		-1.0 1.0	μA μA

AC Electrical Characteristics* $T_A=25^{\circ}C$ and $C_L=50$ pF, typical temperature coefficient for all values of $V_{DD}=0.3\%/^{\circ}C$

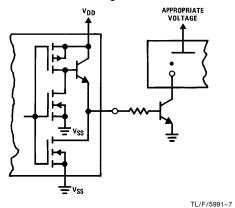
Symbol	Parameter	Conditions		l lmita			
Зуппоп	raiametei	Conditions	Min	Тур	Max	Units	
C _{IN}	Input Capacitance	$V_{IN} = 0$		5.0	7.5	pF	
t _r	Output Rise Time	$V_{DD} = 5V$		40	80	ns	
	(Figure 1a)	$V_{DD} = 10V$		30	60	ns	
		$V_{DD} = 15V$		25	50	ns	
t _f	Output Fall Time	$V_{DD} = 5V$		125	250	ns	
	(Figure 1a)	$V_{DD} = 10V$		75	150	ns	
		$V_{DD} = 15V$		65	130	ns	
t _{PLH}	Turn-Off Delay Time	$V_{DD} = 5V$		640	1280	ns	
	(Data) <i>(Figure 1a)</i>	$V_{DD} = 10V$		250	500	ns	
		$V_{DD} = 15V$		175	350	ns	
t _{PHL}	Turn-On Delay Time	$V_{DD} = 5V$		720	1440	ns	
	(Data) <i>(Figure 1a)</i>	$V_{DD} = 10V$		290	580	ns	
		$V_{DD} = 15V$		195	400	ns	
t _{PLH}	Turn-Off Delay Time	$V_{DD} = 5V$		320	640	ns	
	(Blank) <i>(Figure 1a)</i>	$V_{DD} = 10V$		130	260	ns	
	·	$V_{DD} = 15V$		100	200	ns	
t _{PHL}	Turn-On Delay Time	$V_{DD} = 5V$		485	970	ns	
	(Blank) <i>(Figure 1a)</i>	$V_{DD} = 10V$		200	400	ns	
		$V_{DD} = 15V$		160	320	ns	
t _{PLH}	Turn-Off Delay Time	$V_{DD} = 5V$		313	625	ns	
	(Lamp Test) (Figure 1a)	$V_{DD} = 10V$		125	250	ns	
		$V_{DD} = 15V$		90	180	ns	
t _{PHL}	Turn-On Delay Time	$V_{DD} = 5V$		313	625	ns	
	(Lamp Test) (Figure 1a)	$V_{DD} = 10V$		125	250	ns	
		$V_{DD} = 15V$		90	180	ns	
tSETUP	Setup Time	$V_{DD} = 5V$	180	90		ns	
	(Figure 1b)	$V_{DD} = 10V$	76	38		ns	
		$V_{DD} = 15V$	40	20		ns	
tHOLD	Hold Time	$V_{DD} = 5V$	0	-90		ns	
	(Figure 1b)	$V_{DD} = 10V$	0	-38		ns	
		$V_{DD} = 15V$	0	-20		ns	
PW_{LE}	Minimum Latch Enable	$V_{DD} = 5V$	520	260		ns	
	Pulse Width (Figure 1c)	$V_{DD} = 10V$	220	110		ns	
		$V_{DD} = 15V$	130	65		ns	

^{*}AC Parameters are guaranteed by DC correlated testing.

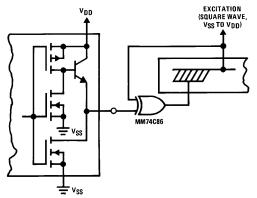


Typical Applications (Continued)

Gas Discharge Readout



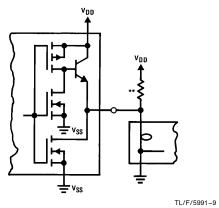
Liquid Crystal (LC) Readout



TL/F/5991-8

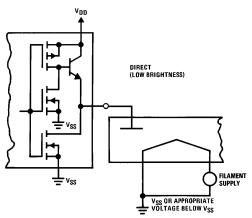
Direct DC drive of LC's not recommended for life of LC readouts.

Incandescent Readout

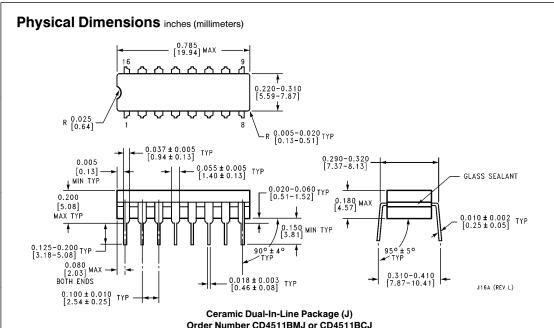


**A filament pre-warm resistor is recommended to reduce filament thermal shock and increase the effective cold resistance of the filament.

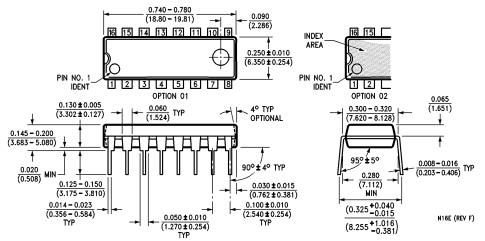
Fluorescent Readout



TL/F/5991-10



Physical Dimensions inches (millimeters) (Continued)



Molded Dual-In-Line Package (N)
Order Number CD4511BMN or CD4511BCN
NS Package Number N16E

LIFE SUPPORT POLICY

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